
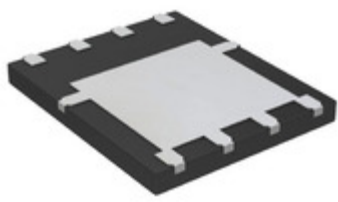
	<p>SIDR392DP-T1-GE3</p>
	<p>Manufacturer Part Number: SIDR392DP-T1-GE3</p> <p>Manufacturer/Brand: Electro-Films (EFI) / Vishay</p> <p>Part of Description: MOSFET N-CHAN 30V</p> <p>Datasheets: 1.SIDR392DP-T1-GE3.pdf 2.SIDR392DP-T1-GE3.pdf</p> <p>RoHs Status:  Lead free / RoHS</p> <p>Stock Condition: Compliant New original, 2673 pcs Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	



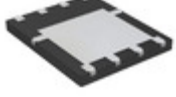
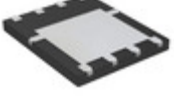
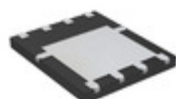
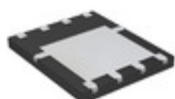
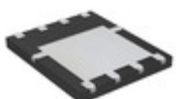

Specifications

Part Number	SIDR392DP-T1-GE3
Manufacturer	Electro-Films (EFI) / Vishay
Description	MOSFET N-CHAN 30V
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2673 pcs Stock
Vgs(th) (Max) @ Id	2.2V @ 250µA
Vgs (Max)	+20V, -16V
Technology	MOSFET (Metal Oxide)
Supplier Device Package	PowerPAK® SO-8DC
Series	TrenchFET® Gen IV
Rds On (Max) @ Id, Vgs	0.62 mOhm @ 20A, 10V
Power Dissipation (Max)	6.25W (Ta), 125W (Tc)
Packaging	Tape & Reel (TR)
Package / Case	PowerPAK® SO-8
Other Names	SIDR392DP-T1-GE3TR
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Manufacturer Standard Lead Time	32 Weeks
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Input Capacitance (Ciss) (Max) @ Vds	9530pF @ 15V
Gate Charge (Qg) (Max) @ Vgs	188nC @ 10V
FET Type	N-Channel
FET Feature	-
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Drain to Source Voltage (Vdss)	30V
Detailed Description	N-Channel 30V 82A (Ta), 100A (Tc) 6.25W (Ta), 125W
Current - Continuous Drain (Id) @ 25°C	82A (Ta), 100A (Tc)

SIDR392DP-T1-GE3 Electronic Components is 100% New Original from YIC Distributor, Search SIDR392DP-T1-GE3 Datasheets, PDF, Inventory at Y-IC.com Online, Order SIDR392DP-T1-GE3 Electro-Films (EFI) / Vishay with Warrantied and Confidence. Ship by DHL/FedEx/TNT/UPS Express. Support Payment with Telegraphic Transfer(T/T) or PayPal.

RFQ SIDR392DP-T1-GE3 Email: Info@Y-IC.com

You May Be Also Be interested

<p>In:</p>  <p>SIDC85D170HX1SA2 International Rectifier (Infineon Technologies) DIODE GEN PURP 1.7KV 150A WAFER</p>	 <p>SIDR638DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 100A SO-8</p>	 <p>SIDR140DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 25V PPAK SO-8DC</p>	 <p>SIDR622DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 150V</p>
 <p>SIDR402DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 40V PPSO-8DC</p>	 <p>SIDR610DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 200V PPAK SO-8DC</p>	 <p>SIDR626DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 60V</p>	 <p>SIDC85D170H Infineon Technologies DIODE GEN PURP 1.7KV 150A WAFER</p>

SIDR392DP-T1-GE3 Related keyword

More

SIDR392DP-T1-GE3 Electro-Films (EFI) / Vishay	SIDR392DP-T1-GE3 Data Sheet	SIDR392DP-T1-GE3 Datasheets	SIDR392DP-T1-GE3 PDF	Electro-Films (EFI) / Vishay SIDR392DP-T1-GE3
SIDR392DP-T1-GE3 Electronic	SIDR392DP-T1-GE3 Components	SIDR392DP-T1-GE3 Distributor	SIDR392DP-T1-GE3 Image	SIDR392DP-T1-GE3 Part
SIDR392DP-T1-GE3 Price	SIDR392DP-T1-GE3 Manufacturer	SIDR392DP-T1-GE3 Picture	SIDR392DP-T1-GE3 Stock	SIDR392DP-T1-GE3 Inventory
SIDR392DP-T1-GE3 New	SIDR392DP-T1-GE3 Original	SIDR392DP-T1-GE3 Warranted	SIDR392DP-T1-GE3 RFQ	SIDR392DP-T1-GE3 Order Online

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